

Description

The IMX585-AAMJ1 is a diagonal 12.84 mm (Type 1/1.2) CMOS active pixel type solid-state image sensor with a square pixel array and 8.40 M effective pixels. This chip operates with analog 3.3 V, digital 1.1 V, and interface 1.8 V triple power supply, and has low power consumption. High sensitivity, low dark current and no smear are achieved. This chip features an electronic shutter with variable charge-integration time.
(Application: Security cameras)

Features

- ◆ CMOS active pixel type dots
- ◆ Built-in timing adjustment circuit, H/V driver and serial communication circuit
- ◆ Input frequency: 24 MHz / 27 MHz / 37.125 MHz / 72 MHz / 74.25 MHz
- ◆ Number of recommended recording pixels: 3840 (H) × 2160 (V) approx. 8.29M pixel
- ◆ Readout mode
 - All-pixel scan mode
 - 2×2 adjacent pixel binning mode
 - Window cropping mode
 - Horizontal / Vertical direction - Normal / Inverted readout mode
- ◆ Readout rate
 - Maximum frame rate in All-pixel scan mode: 12 bit: 60 frame/s, 10 bit: 90 frame/s
- ◆ High dynamic range (HDR) function
 - Digital overlap HDR
 - Clear HDR
- ◆ Synchronizing sensors function
- ◆ Variable-speed shutter function (resolution 2H units)
- ◆ 10-bit / 12-bit A/D converter
- ◆ CDS / PGA function
 - 0 dB to 30 dB : Analog Gain 30 dB (step pitch 0.3 dB)
 - 30.3 dB to 72 dB : Analog Gain 30 dB + Digital Gain 0.3 dB to 42 dB (step pitch 0.3 dB)
- ◆ Supports I/O
 - CSI-2 serial data output (2 Lane / 4 Lane / 8Lane / 4Lane × 2ch)
 - RAW10 / RAW12 / RAW16 (Clear HDR) output
- ◆ AR coating on cover glass (Both sides)

STARVIS 2

* STARVIS 2 and its logo are registered trademarks or trademarks of Sony Group Corporation or its affiliates. The STARVIS 2 is back-illuminated pixel technology used in CMOS image sensors for security camera applications. It features a sensitivity of 2000 mV or more per 1 μm² (color product, when imaging with a 706 cd/m² light source, F5.6 in 1 s accumulation equivalent). It also has a wide dynamic range (AD 12 bit) of more than 8 dB compared to STARVIS for the same pixel size in a single exposure, and achieves high picture quality in the visible-light and near infrared light regions.

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Device Structure

- ◆ CMOS image sensor
- ◆ Image size Diagonal 12.84 mm (Type 1/1.2) approx. 8.40 M pixels, All pixels
- ◆ Total number of pixels 3856 (H) × 2220 (V) approx. 8.56 M pixels
- ◆ Number of effective pixels 3856 (H) × 2180 (V) approx. 8.40 M pixels
- ◆ Number of active pixels 3856 (H) × 2176 (V) approx. 8.39 M pixels
- ◆ Number of recommended recording pixels 3840 (H) × 2160 (V) approx. 8.29 M pixels
- ◆ Unit cell size 2.9 μm (H) × 2.9 μm (V)
- ◆ Optical black
Horizontal (H) direction: Front 0 pixels, rear 0 pixels
Vertical (V) direction: Front 20 pixels, rear 0 pixels
- ◆ Dummy
Horizontal (H) direction: Front 0 pixels, rear 0 pixels
Vertical (V) direction: Front 0 pixels, rear 0 pixels
- ◆ Package 122 pin LGA

Image Sensor Characteristics

(Tj = 60 °C)

Item		Value	Remarks
Sensitivity	Typ.	31300 Digit/lx/s	12 bit converted value
Saturation signal	Min.	3895 Digit	12 bit converted value

Basic Drive Mode

Drive mode	Recommended number of recording pixels	Maximum frame rate [frame/s]	Output interface	ADC [bit]
All-pixel	3840 (H) × 2160 (V) approx. 8.29 M pixels	90	CSI-2	10
2×2 adjacent pixel binning mode	1920 (H) × 1080 (V) approx. 2.07 M pixels	90	CSI-2	10

